

High Voltage LED Series Chip on Board

LCoo6D – Gen.1



High efficacy COB LED package
well-suited for use in spotlight applications

Features & Benefits

- Chip on Board (COB) solution makes it easy to design in
- Simple assembly reduces manufacturing cost
- Low thermal resistance
- InGaN/GaN MQW LED with long time reliability

Applications

- Spotlight / Downlight
- LED Retrofit Bulbs
- Outdoor Illumination



SAMSUNG

Table of Contents

1.	Characteristics	-----	3
2.	Product Code Information	-----	5
3.	Typical Characteristics Graphs	-----	9
4.	Outline Drawing & Dimension	-----	12
5.	Reliability Test Items & Conditions	-----	13
6.	Label Structure	-----	14
7.	Packing Structure	-----	15
8.	Precautions in Handling & Use	-----	17

1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	T_a	-40 ~ +105	°C	-
Storage Temperature	T_{stg}	-40 ~ +120	°C	-
LED Junction Temperature	T_J	140	°C	-
Case Temperature	T_c	105	°C	-
Forward Current	I_F	460	mA	-
Power Dissipation	P_D	17.2	W	-
ESD (HBM)	-	±2	kV	-
ESD (MM)	-	±0.5	kV	-

b) Electro-optical Characteristics ($I_F = 180 \text{ mA}$, $T_J = 85 \text{ °C}$)

Item	Unit	Rank	Min.	Typ.	Max.
Forward Voltage (V_F)	V	YZ	31.8	34.6	37.5
Color Rendering Index (R_a)	-	5	80	-	-
		7	90		
Thermal Resistance (junction to chip point)	°C/W		-	2.4	-
Beam Angle	°		-	115	-
Nominal Power	W			6.4	

Notes:

- 1) The COB is tested in pulsed condition at rated test current (10 ms pulse width) and rated temperature ($T_J = T_C = T_a = 85 \text{ °C}$)
- 2) Samsung maintains measurement tolerance of: forward voltage = ±5 %, CRI = ±1
- 3) Refer to the derating curve, '3. Typical Characteristics Graph' designed within the range.

c) Luminous Flux Characteristics (I_F = 180 mA)

CRI (R _a) Min.	Nominal CCT (K)	Flux Rank	Flux @ T _J = 85 °C (lm)		
			Min.	Typ.	Max.
80	2700	E9	791	832	-
		D1	832	874	-
	3000	F3	831	875	-
		D1	875	919	-
	3500	F5	857	902	-
		D1	902	947	-
	4000	F8	877	923	-
		D1	923	969	-
	5000	F8	882	928	-
		D1	928	975	-
	5700	F8	882	928	-
		D1	928	975	-
	6500	F8	872	918	-
		D1	918	964	-

CRI (R _a) Min.	Nominal CCT (K)	Flux Rank	Flux @ T _J = 85 °C (lm)		
			Min.	Typ.	Max.
90	2700	D7	673	709	-
		D1	709	744	-
	3000	E9	706	743	-
		D1	743	780	-
	3500	E0	730	768	-
		D1	768	807	-
	4000	E4	745	784	-
		D1	784	824	-
	5000	E4	748	787	-
		D1	787	827	-

Notes:

- 1) The COB is tested in pulsed operating condition at rated test current (10 ms pulse width) and rated temperature ($T_j = T_c = 85^\circ\text{C}$).
- 2) Samsung maintains measurement tolerance of: Luminous flux = $\pm 7\%$, CRI = ± 1

2. Product Code Information

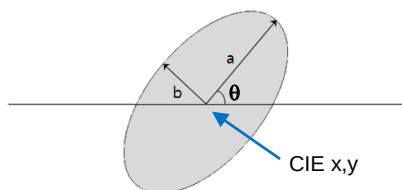
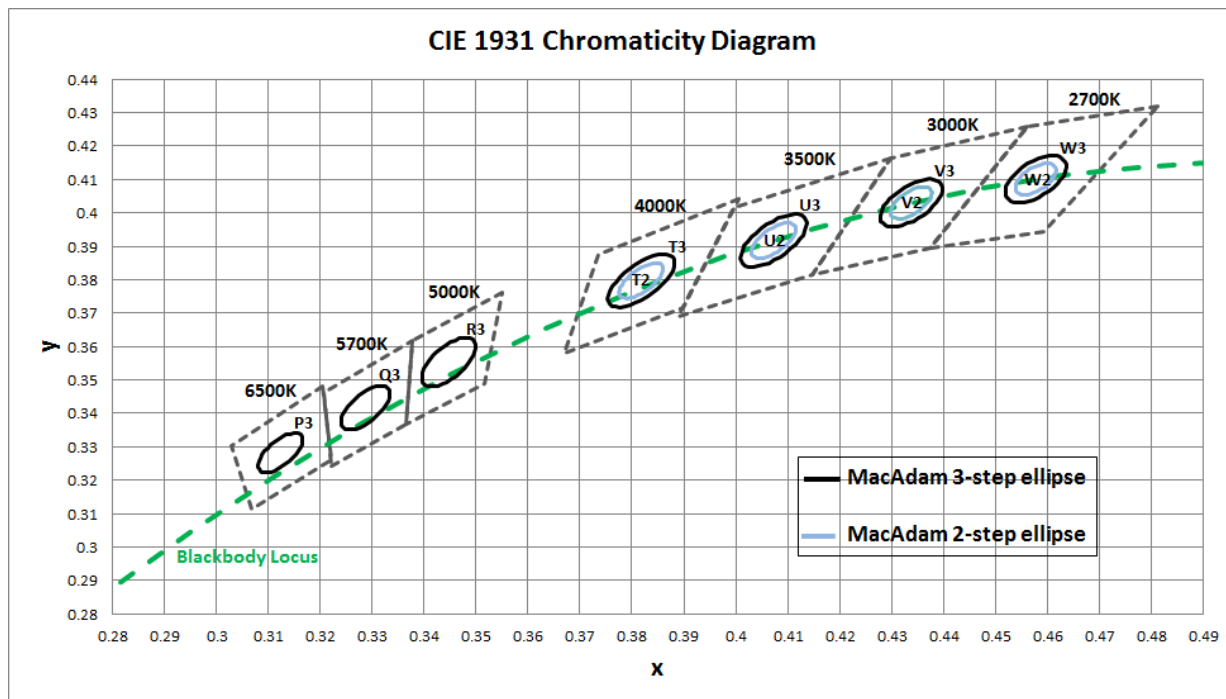
1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	H	W	H	A	H	D	N	B	2	5	Y	Z	W	3	E	9

Digit	PKG Information	Code	Specification
1 2 3	Samsung Package High Power	SPH	
4 5	Color	WH	White
6	Product Version	A	
7 8	Form Factor	HD	COB
9	Lens Type	N	No lens
10	Wattage or Model	B	LC006D
11	Internal Code	2	
12	CRI & Sorting Temperature	5	Min. 80 (85°C)
		7	Min. 90 (85°C)
13 14	Forward Voltage (V)	YZ	31.8~37.5
15	CCT (K)	W V U T R Q P	2700K 3000K 3500K 4000K 5000K 5700K 6500K
16	MacAdam Step	2 3	MacAdam 2-step MacAdam 3-step
17 18	Luminous Flux (Lm)	D7 E0 E4 E9 F3 F5 F7 F8 D1	Min. 670 Min. 700 Min. 740 Min. 790 Min. 830 Min. 850 Min. 870 Min. 880 Add Rank

a) Binning Structure ($I_F = 180 \text{ mA}$, $T_J = 85 \text{ }^\circ\text{C}$)

CRI (R _a) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Flux Rank	Flux Range (Φ_v , lm)
80	2700	SPHWAHDNB25YZW2E9	YZ	W2	E9	791 ~
		SPHWAHDNB25YZW3E9		W3		
		SPHWAHDNB25YZW2D1		W2	D1	832 ~
		SPHWAHDNB25YZW3D1		W3		
	3000	SPHWAHDNB25YZV2F3	YZ	V2	F3	831 ~
		SPHWAHDNB25YZV3F3		V3		
		SPHWAHDNB25YZV2D1		V2	D1	875 ~
		SPHWAHDNB25YZV3D1		V3		
	3500	SPHWAHDNB25YZU2F5	YZ	U2	F5	857 ~
		SPHWAHDNB25YZU3F5		U3		
		SPHWAHDNB25YZU2D1		U2	D1	902 ~
		SPHWAHDNB25YZU3D1		U3		
	4000	SPHWAHDNB25YZT2F8	YZ	T2	F8	877 ~
		SPHWAHDNB25YZT3F8		T3		
		SPHWAHDNB25YZT2D1		T2	D1	923 ~
		SPHWAHDNB25YZT3D1		T3		
	5000	SPHWAHDNB25YZR3F8	YZ	R2	F8	882 ~
		SPHWAHDNB25YZR3D1		R3	D1	928 ~
	5700	SPHWAHDNB25YZQ3F8	YZ	Q2	F8	882 ~
		SPHWAHDNB25YZQ3D1		Q3	D1	928 ~
	6500	SPHWAHDNB25YZP3F7	YZ	P2	F7	872 ~
		SPHWAHDNB25YZP3D1		P3	D1	918 ~

CRI (R _a) Min.	Nominal CCT (K)	Product Code	V _F Rank	Color Rank	Flux Rank	Flux Range (Φ _v , lm)
90	2700	SPHWWAHDNB27YZW2D7	YZ	W2	D7	673 ~
		SPHWWAHDNB27YZW3D7		W3		
		SPHWWAHDNB27YZW2D1		W2	D1	709 ~
		SPHWWAHDNB27YZW3D1		W3		
	3000	SPHWWAHDNB27YZV2E9	YZ	V2	E9	706 ~
		SPHWWAHDNB27YZV3E9		V3		
		SPHWWAHDNB27YZV2D1		V2	D1	743 ~
		SPHWWAHDNB27YZV3D1		V3		
	3500	SPHWWAHDNB27YZU2E0	YZ	U2	E0	730 ~
		SPHWWAHDNB27YZU3E0		U3		
		SPHWWAHDNB27YZU2D1		U2	D1	768 ~
		SPHWWAHDNB27YZU3D1		U3		
	4000	SPHWWAHDNB27YZT2E4	YZ	T2	E4	745 ~
		SPHWWAHDNB27YZT3E4		T3		
		SPHWWAHDNB27YZT2D1		T2	D1	784 ~
		SPHWWAHDNB27YZT3D1		T3		
	5000	SPHWWAHDNB27YZR3E4	YZ	R3	E4	748 ~
		SPHWWAHDNB27YZR3D1		R3	D1	787 ~

b) Chromaticity Region & Coordinates ($I_F = 180 \text{ mA}$, $T_J = 85^\circ\text{C}$)


MacAdam Ellipse (W2, W3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4578	0.4101	53.70	0.0054	0.0028
3-step	0.4578	0.4101	53.70	0.0081	0.0042

MacAdam Ellipse (V2, V3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4338	0.403	53.22	0.0056	0.0027
3-step	0.4338	0.4030	53.22	0.0083	0.0041

MacAdam Ellipse (U2, U3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.4073	0.3917	54.00	0.0062	0.0028
3-step	0.4073	0.3917	54.00	0.0093	0.0041

MacAdam Ellipse (T2, T3)					
Step	CIE x	CIE y	θ	a	b
2-step	0.3818	0.3797	53.72	0.0063	0.0027
3-step	0.3818	0.3797	53.72	0.0094	0.0040

MacAdam Ellipse (R3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3447	0.3553	59.62	0.0082	0.0035

MacAdam Ellipse (Q3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3287	0.3417	59.0950	0.0075	0.0032

MacAdam Ellipse (P3)					
Step	CIE x	CIE y	θ	a	b
3-step	0.3123	0.3282	58.5700	0.0067	0.0029

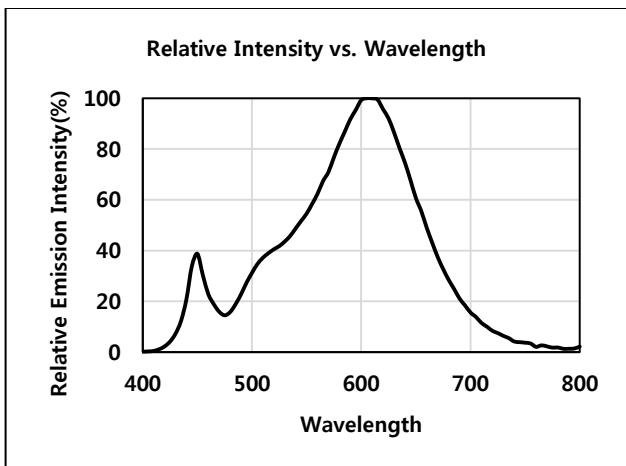
Note:

Samsung maintains measurement tolerance of: $C_x, C_y = \pm 0.005$

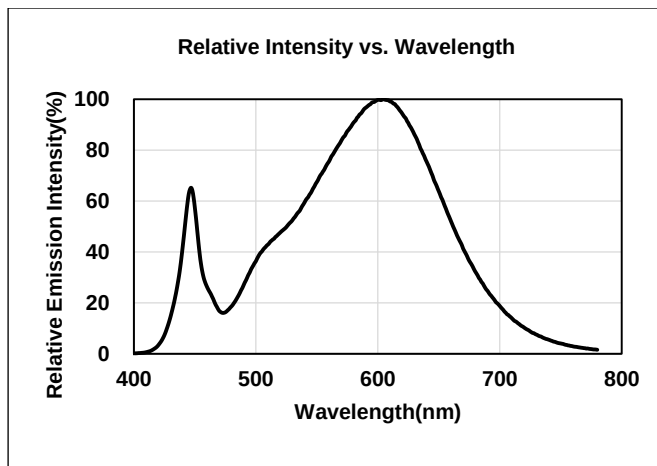
3. Typical Characteristics Graphs

b) Beam Angle Characteristics ($I_F = 180 \text{ mA}$, $T_J = 85^\circ\text{C}$)

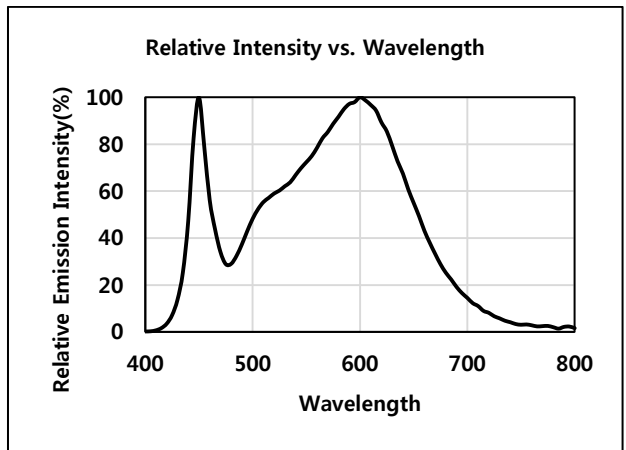
CCT: 2700 K (80 CRI)



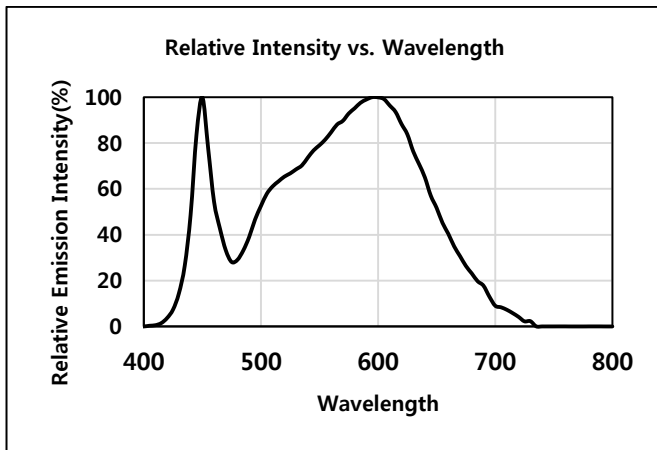
CCT: 3000 K (80 CRI)



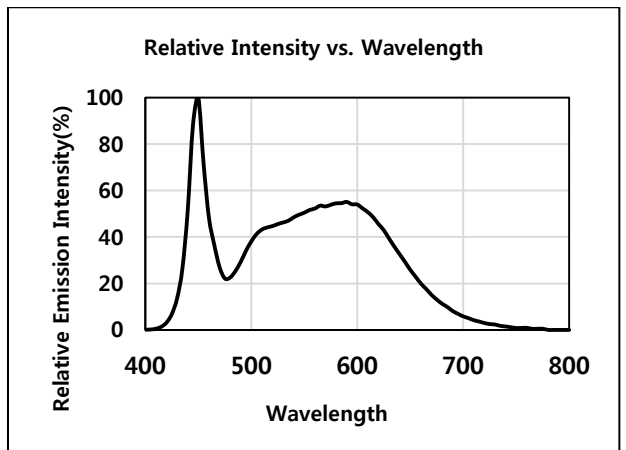
CCT: 3500 K (80 CRI)



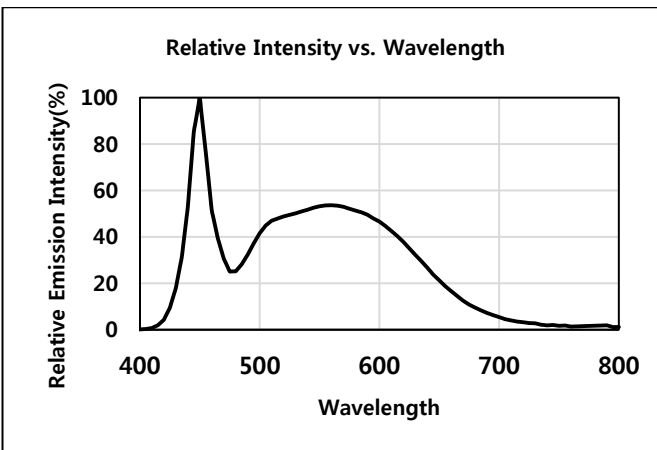
CCT: 4000 K (80 CRI)



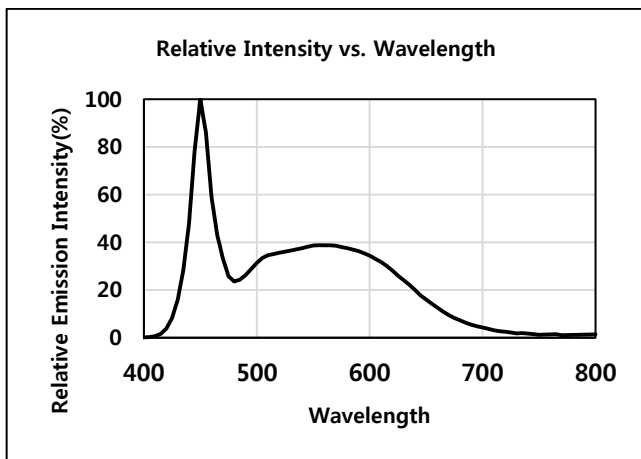
CCT: 5000 K (80 CRI)



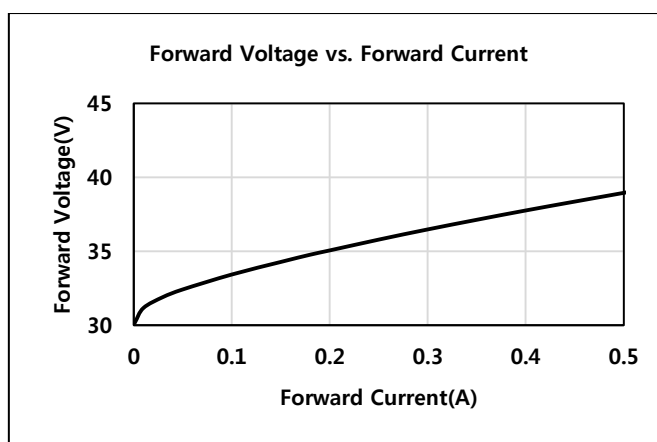
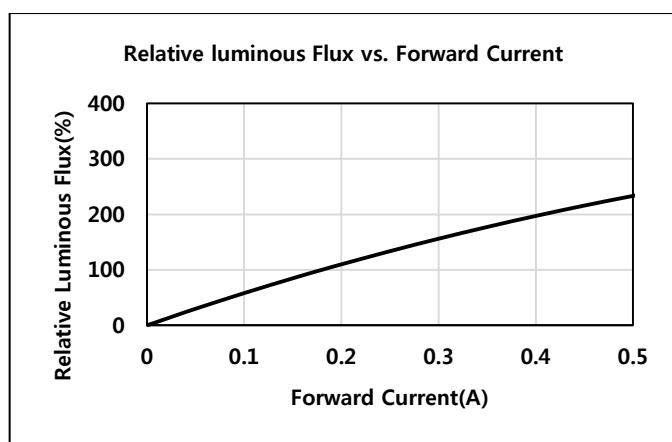
CCT: 5700 K (80 CRI)



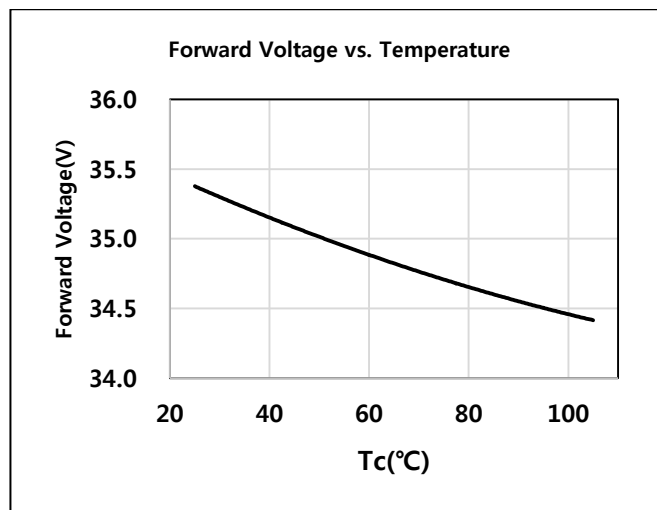
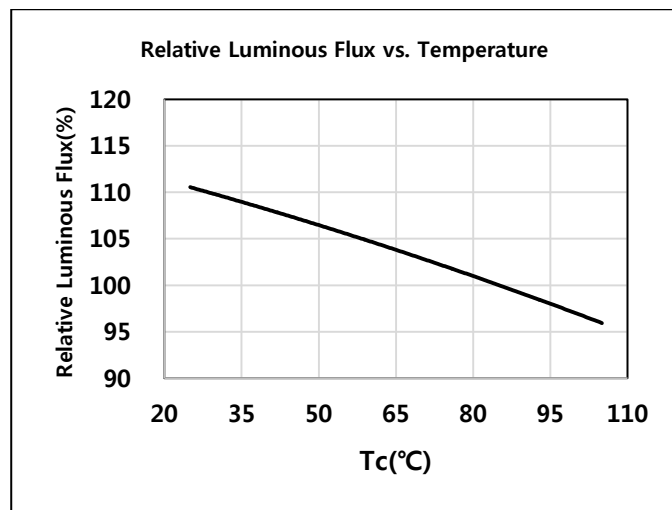
CCT: 6500 K (80 CRI)



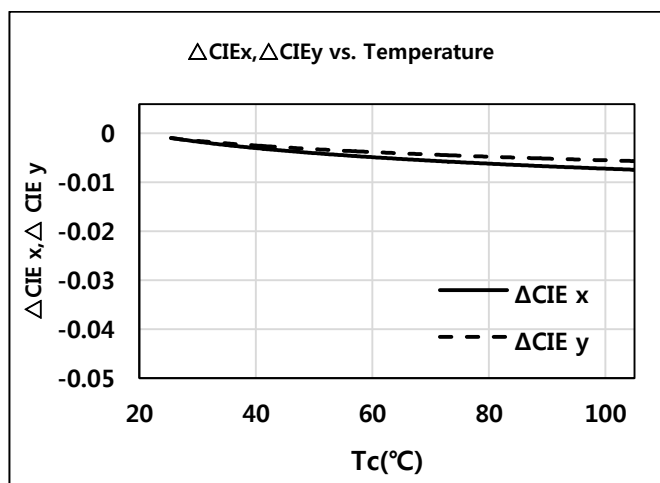
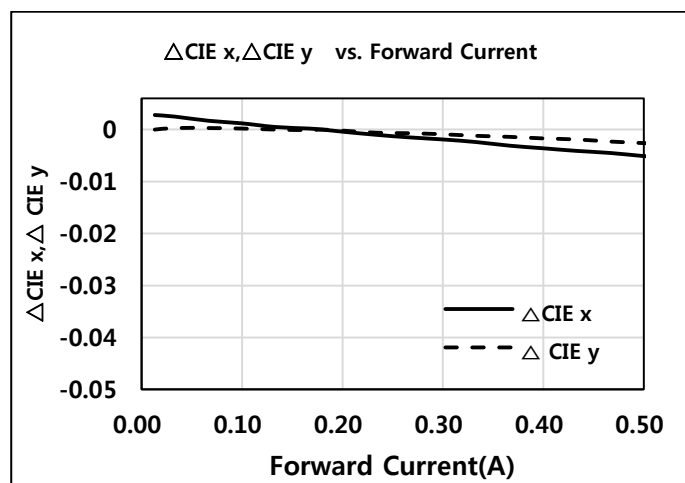
b) Forward Current Characteristics ($T_J = 85^\circ\text{C}$)



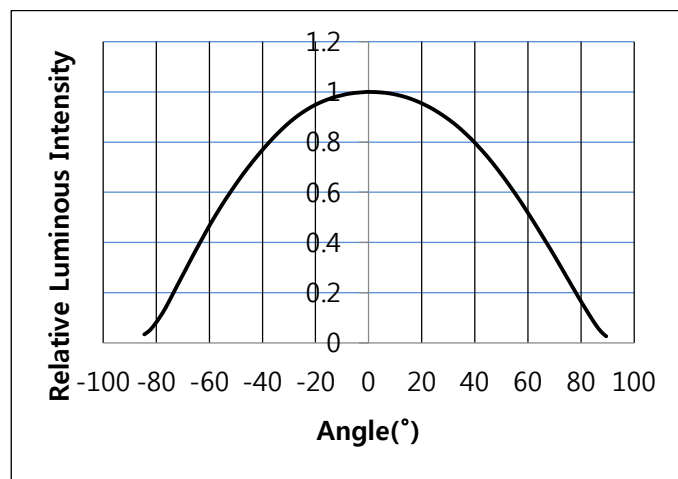
c) Temperature Characteristics ($I_F = 180\text{mA}$)



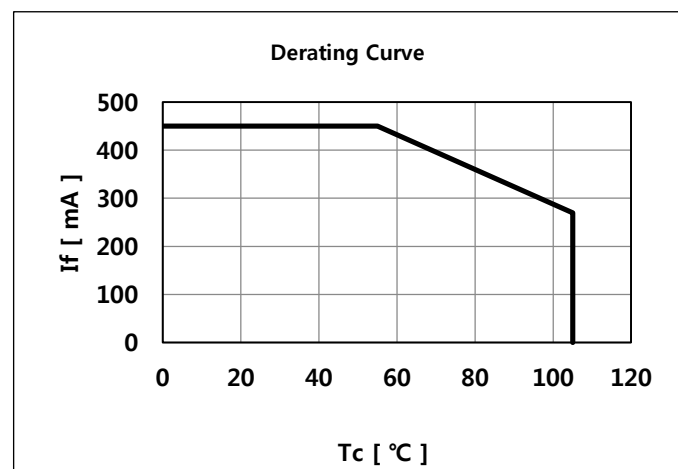
d) Color Shift Characteristics ($T_J = 85^\circ\text{C}$, CRI 80+)



e) Beam Angle Characteristics ($I_F = 180\text{ mA}$, $T_J = 85^\circ\text{C}$)



f) Derating Characteristics



5. Reliability Test Items & Conditions

a) Test Items

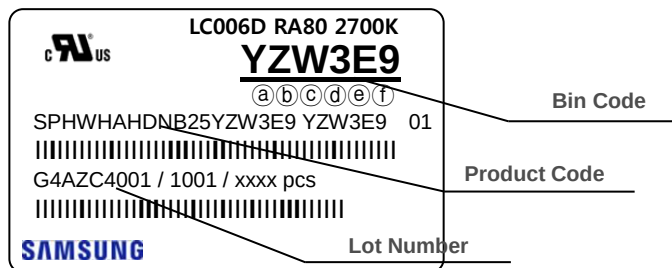
Test Item	Test Condition	Test Hour / Cycle
High Temperature Humidity Life Test	60 °C, 90 % RH., DC Derating, I_F	1000 h
High Temperature Life Test	85 °C, DC Derating, I_F	1000 h
Low Temperature Life Test	-40 °C, DC , $I_F = 320$ mA	1000 h
Pulsed Operating Life Test	55 °C, Pulse width 100 μ s, duty cycle 3 %	1000 h
High Temperature Storage	120 °C	1000 h
Low Temperature Storage	-40 °C	1000 h
Temperature Humidity Storage	60 °C, 90% RH	1000h
Temperature Cycle On/Off Test	-40 °C / 85 °C each 20 min, 30 min transfer power on/off each 5 min, DC Derating, $I_F = \text{max}$	100 cycles
ESD (HBM)	R_1 : 10 M Ω R_2 : 1.5 k Ω C: 100 pF V: ± 2 kV	5 times
ESD (MM)	R_1 : 10 M Ω R_2 : 0 k Ω C: 200 pF V: ± 0.2 kV	5 times
Vibration Test	20 ~ 80 Hz (displacement: 0.06 inch, max. 20 g) 80 ~ 2 kHz (max. 20 g) min. frequency $\leftrightarrow$ max. frequency 4 min transfer	4 times
Mechanical Shock Test	1500 g, 0.5 ms each of the 6 surfaces (3 axis x 2 sides)	5 times
Sulfur Resistance	25 °C, 75%, H ₂ S 15 ppm	504h

b) Criteria for Judging the Damage

Item	Symbol	Test Condition ($T_c = 25$ °C)	Limit	
			Min.	Max.
Forward Voltage	V_F	$I_F = 180$ mA	L.S.L. * 0.9	U.S.L. * 1.1
Luminous Flux	Φ_v	$I_F = 180$ mA	L.S.L * 0.7	U.S.L * 1.3

6. Label Structure

a) Label Structure



Note: Denoted bin code and product code above is only an example (see description on page 5)

Bin Code:

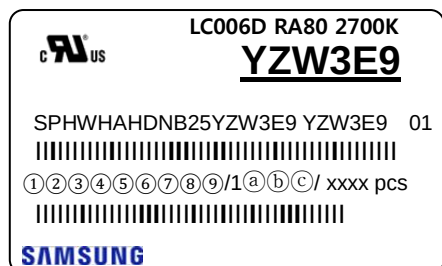
ⒶⒷ: Forward Voltage bin (refer to page 11)

ⒸⒹ: Chromaticity bin (refer to page 9-10)

ⒺⒻ: Luminous Flux bin (refer to page 6)

b) Lot Number

The lot number is composed of the following characters:



① ③④⑤⑥⑦⑧⑨ / 1ⒶⒷⒸ / xxxx pcs

① : Production site (S: Giheung, Korea, G: Tianjin, China)

② : 4 (LED)

③ : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

④ : Year (Z: 2015, A: 2016, B: 2017...)

⑤ : Month (1~9, A, B, C)

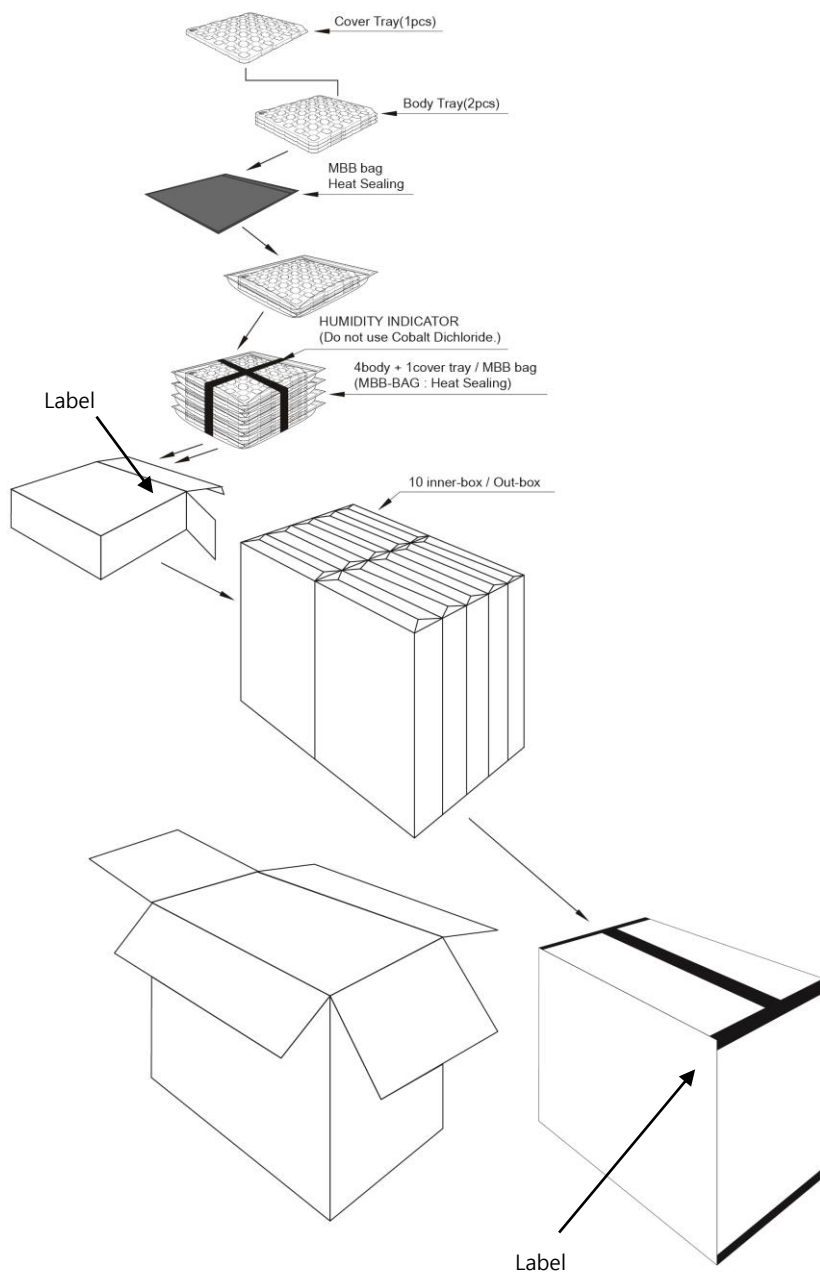
⑥⑦⑧⑨ : Day (1~9, A, B~V)

ⒶⒷⒸ : Product serial number (001 ~ 999)

7. Packing Structure

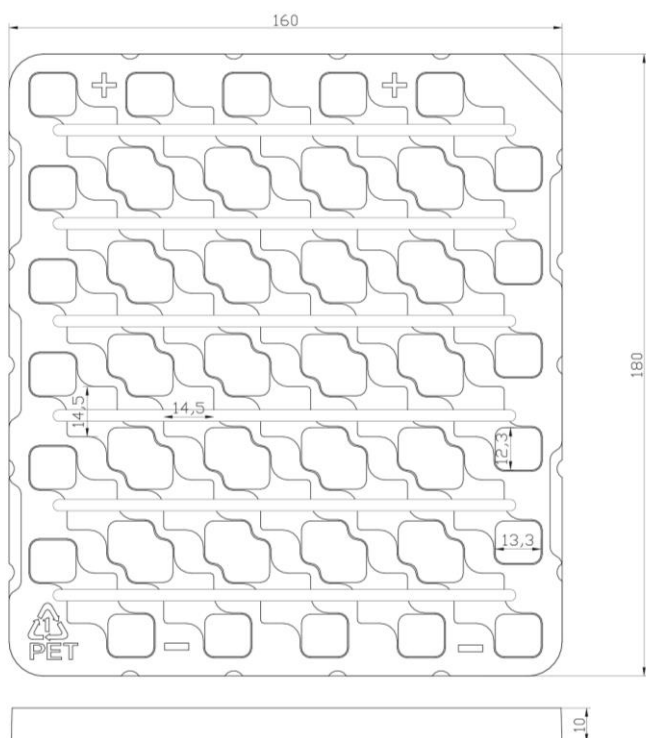
Packing material	Max. quantity in pcs of COB	Dimension(mm)			
		Length	Width	Height	Tolerance
Tray	30	160	180	10	1.0
Aluminum Bag	60(2 trays)	210	241		10
Inner Box	240	230	84	260	2
Outer Box	2400	476	445	272	5

a) Packing Structure

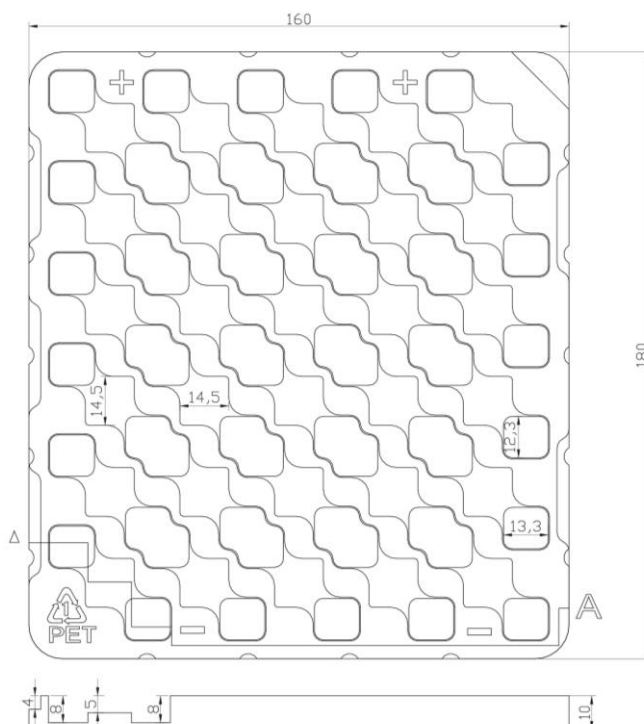


b) Tray

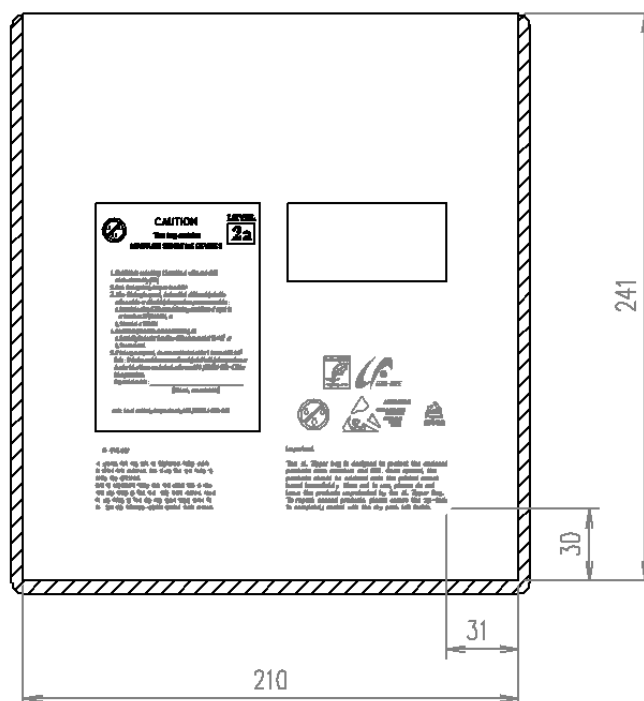
① Cover



② Body

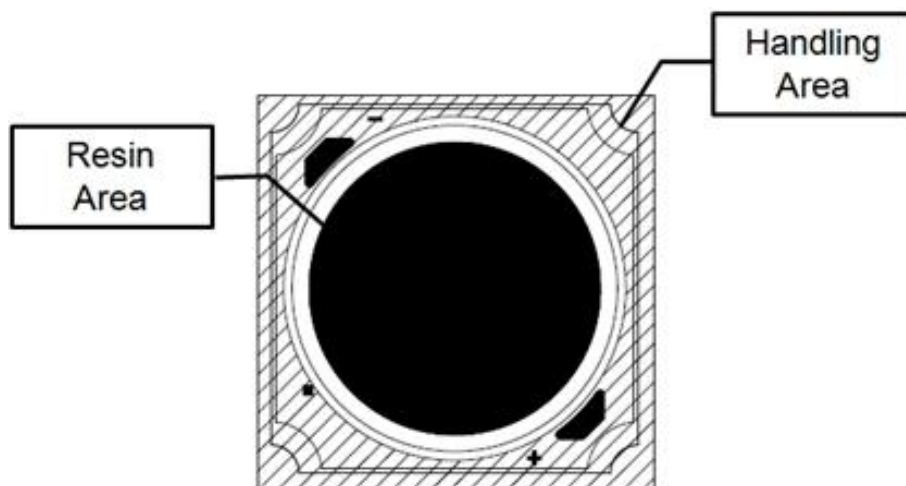


c) Aluminum Vinyl Packing Bag



8. Precautions in Handling & Use

- 1) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 2) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed with a nitrogen-filled container (shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH).
- 3) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
 - b. Stored at <10 % RH
- 4) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 5) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 6) Devices must be baked for 1 hour at 60 ± 5 °C, if baking is required.
- 7) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 8) The thermal management is one of the most critical factors for the LED lighting system. Especially the LED junction temperature should not exceed the absolute maximum rating while operation of LED lighting system.
For more information, please refer to Application Note 'Mechanical & Thermal Guide for COB'.
- 9) In case of driving LEDs around the minimum current level (I_{f_min}), chips might exhibit different brightness due to the variation in I-V characteristics of each one. This is normal and does not adversely affect the performance of product.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) The resin area is very sensitive, please do not handle, press, touch, rub, clean, or pick by with tweezers on it. Instead, please pick at the handling area as indicated below.



Legal and additional information.

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The Samsung logo, consisting of the word "SAMSUNG" in a bold, blue, sans-serif font.